# NL17SG34

# **Single Buffer**

The NL17SG34 MiniGate<sup>™</sup> is an advanced high-speed CMOS Buffer in ultra-small footprint.

The NL17SG34 input structures provides protection when voltages up to 4.6 V are applied.

## Features

- Wide Operating  $V_{CC}$  Range: 0.9 V to 3.6 V
- High Speed:  $t_{PD}$  = 2.3 ns (Typ) at  $V_{CC}$  = 3.0 V,  $C_L$  = 15 pF
- Low Power Dissipation:  $I_{CC} = 0.5 \ \mu A \ (Max)$  at  $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- These are Pb-Free and Halide-Free Devices

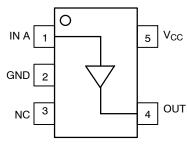


Figure 1. SOT-953 (Top Thru View)

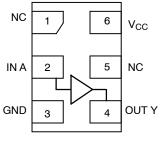
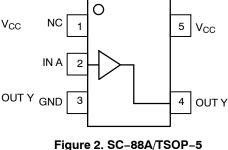


Figure 3. UDFN (Top View)



(Top View)

1

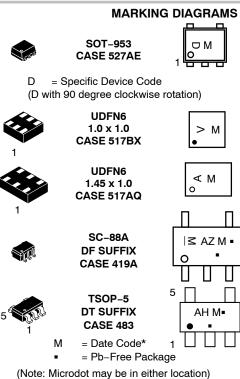
Figure 4. Logic Symbol

IN A



# **ON Semiconductor®**

http://onsemi.com



(Note: Microdot may be in either location) \*Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT						
	SOT-953 SC88A/TSOP5 UDFN6					
1	IN A	NC	NC			
2	GND	IN A	IN A			
3	NC	GND	GND			
4	OUT Y	OUT Y	OUT Y			
5	V <sub>CC</sub>	V <sub>CC</sub>	NC			
6			V <sub>CC</sub>			

#### FUNCTION TABLE

A Input	Y Output
L	L
Н	Н

#### **ORDERING INFORMATION**

OUT Y

See detailed ordering and shipping information on page 5 of this data sheet.

# MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage		–0.5 to +5.5	V
V <sub>IN</sub>	DC Input Voltage		-0.5 to +4.6	V
V <sub>OUT</sub>	DC Output Voltage	Output at High or Low State Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> +0.5 -0.5 to +4.6	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-20	mA
Ι <sub>ΟΚ</sub>	DC Output Diode Current	V <sub>OUT</sub> < GND	-20	mA
I <sub>OUT</sub>	DC Output Source/Sink Current		±20	mA
I <sub>CC</sub>	DC Supply Current per Supply Pin		±20	mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±20	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds		260	°C
TJ	Junction Temperature Under Bias		+150	°C
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
$V_{ESD}$	ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3)	>2000 >100	V
ILATCHUP	Latchup Performance Above V <sub>CC</sub> ar	nd Below GND at 125°C (Note 4)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.
Tested to EIA/JESD22-A114-A.
Tested to EIA/JESD22-A115-A.

4. Tested to EIA/JESD78.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Characteristics	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	0.9	3.6	V
V <sub>IN</sub>	Digital Input Voltage	0.0	3.6	V
V <sub>OUT</sub>	Output Voltage Output at High or Low Stat Power-Down Mode (V <sub>CC</sub> = 0 V		V <sub>CC</sub> 3.6	V
T <sub>A</sub>	Operating Temperature Range	-55	+125	°C
$\Delta t / \Delta V$	Input Transition Rise or Fail Rate $V_{CC}$ = 3.3 V ± 0.3 V	/ 0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# DC ELECTRICAL CHARACTERISTICS

					T <sub>A</sub> =	25°C		_ = o +125°C	
Symbol	Parameter	Conc	Conditions	V <sub>CC</sub> (V)	Min	Max	Min	Max	Unit
V <sub>IH</sub> H	High-Level Input			0.9	V <sub>CC</sub>		V <sub>CC</sub>		V
	Voltage			1.1 to 1.3	0.7xV <sub>CC</sub>		0.7xV <sub>CC</sub>		
				1.4 to 1.6	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		
				1.65 to 1.95	$0.65 \mathrm{xV}_{\mathrm{CC}}$		$0.65 \mathrm{xV}_{\mathrm{CC}}$		
				2.3 to 2.7	1.7		1.7		
				3.0 to 3.6	2.0		2.0		
VIL	Low-Level Input			0.9		GND		GND	V
	Voltage			1.1 to 1.3		0.3xV <sub>CC</sub>		0.3xV <sub>CC</sub>	
				1.4 to 1.6		0.35xV <sub>CC</sub>		0.35xV <sub>CC</sub>	
				1.65 to 1.95		0.35xV <sub>CC</sub>		0.35xV <sub>CC</sub>	
				2.3 to 2.7		0.7		0.7	
				3.0 to 3.6		0.8		0.8	
<b>U</b>	High–Level	V <sub>IN</sub> =	I <sub>OH</sub> = -20 μA	0.9	0.75		0.75		V
	Output Voltage	V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	0.75xV <sub>CC</sub>		0.75xV <sub>CC</sub>		
			I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	0.75xV <sub>CC</sub>		0.75xV <sub>CC</sub>		
			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	Vcc-0.45		Vcc-0.45		
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0		2.0		
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48		2.48		
V <sub>OL</sub>	Low-Level	V <sub>IN</sub> =	I <sub>OL</sub> = 20 μA	0.9		0.1		0.1	V
	Output Voltage	V <sub>IH</sub> or V <sub>IL</sub>	l <sub>OL</sub> = 0.3 mA	1.1 to 1.3		$0.25 \mathrm{xV}_{\mathrm{CC}}$		$0.25 \mathrm{xV}_{\mathrm{CC}}$	
			l <sub>OL</sub> = 1.7 mA	1.4 to 1.6		$0.25 \mathrm{xV}_{\mathrm{CC}}$		$0.25 \mathrm{xV}_{\mathrm{CC}}$	
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95		0.45		0.45	1
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7		0.4		0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6		0.4		0.4	
I <sub>IN</sub>	Input Leakage Current	0 ≤	V <sub>IN</sub> ≤ 3.6 V	0 to 3.6		±0.1		±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =	V <sub>CC</sub> or GND	3.6		0.5		10.0	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

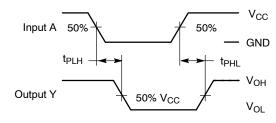
# **NL17SG34**

Symbol	Parameter	Test Condition	V <sub>CC</sub> (V)	-	Γ <sub>A</sub> = 25° C	)		= 0 +125°C															
				Min	Тур	Max	Min	Max	Unit														
t <sub>PLH</sub> ,	Propagation Delay,	$C_L = 10 \text{ pF},$	0.9	-	12.6	15.3	-	19.0	ns														
t <sub>PHL</sub>	A to Y	$R_L = 1 M\Omega$	1.1 to 1.3	-	8.7	13.4	-	15.2															
			1.4 to 1.6	-	4.9	8.5	-	10.0															
			1.65 to 1.95	-	3.8	6.2	-	6.7															
			2.3 to 2.7	-	2.6	3.9	-	4.4															
			3.0 to 3.6	-	2.1	3.1	-	3.7															
		$C_L = 15 \text{ pF},$	0.9	-	13.0	16.6	-	20.8	ns														
		$R_{L} = 1 M\Omega$	1.1 to 1.3	-	8.0	12.5	-	15.7															
			1.4 to 1.6	-	5.4	9.3	-	11.2															
								l									1.65 to 1.95	-	4.2	6.9	-	7.1	
							2.3 to 2.7	-	2.8	4.4	-	5.0											
				3.0 to 3.6	-	2.3	3.4	-	3.9														
		$C_L = 30 \text{ pF},$	0.9	-	14.5	17.6	-	22.4	ns														
		$\vec{R_L} = 1 \ \dot{M}\Omega$ 1.1 to 1.3 –	-	9.5	13.5	-	18.8																
			1.4 to 1.6	-	7.4	11.1	-	15.9															
			1.65 to 1.95	-	5.6	9.2	-	9.6															
			2.3 to 2.7	-	3.7	5.7	-	6.1	1														
			3.0 to 3.6	-	2.9	4.4	-	4.8	1														
C <sub>IN</sub>	Input Capacitance		0 to 3.6		3	-	-	-	pF														
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	f = 10 MHz	0.9 to 3.6	-	4	-	-	-	pF														

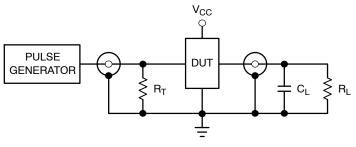
#### AC ELECTRICAL CHARACTERISTICS Input $t_r = t_f = 3.0 \text{ ns}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
5. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# NL17SG34







 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 6. Test Circuit

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NL17SG34P5T5G	SOT-953 (Pb-Free)	8000 / Tape & Reel
NL17SG34DFT2G	SC-88A (Pb-Free)	3000 / Tape & Reel
NL17SG34DTT1G*	TSOP–5 (Pb–Free)	3000 / Tape & Reel
NL17SG34AMUTCG*	UDFN6 1.45x1 mm (Pb-Free)	3000 / Tape & Reel
NL17SG34CMUTCG*	UDFN6 1x1 mm (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*In Development

# **NSEM**



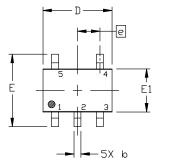
#### SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE M**

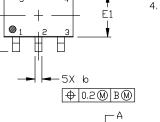
NDTES: 1.

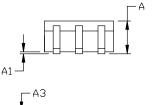
2.

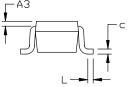
З.

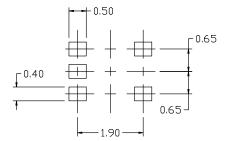
DATE 11 APR 2023











#### RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

DIM	MILLIMETERS				
MIU	MIN,	NDM.	MAX.		
A	0.80	0.95	1.10		
A1			0.10		
A3	0.20 REF				
b	0.10	0.20	0.30		
С	0.10		0.25		
D	1.80	2.00	5'50		
E	2.00	2.10	5'50		
E1	1.15	1.25	1.35		
e	0.65 BSC				
L	0.10	0.15	0.30		

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS,

OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

CONTROLLING DIMENSION: MILLIMETERS 419A-01 DBSOLETE, NEW STANDARD 419A-02

# **GENERIC MARKING**





\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

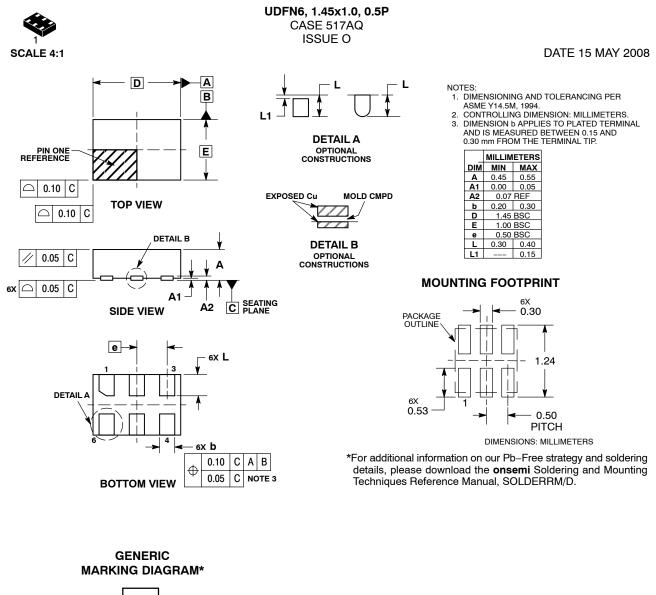
Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR	STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE	STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1	STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2	STYLE 5: PIN 1. CATHODE 2. COMMON ANOD 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4	E
STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE	STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 1 5. COLLECTOR	STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER	STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE	Note: Please refer to style callout. If style to out in the datasheet r datasheet pinout or p	ype is not called efer to the device
DOCUMENT NUMBER:	98ASB42984B			ot when accessed directly from when stamped "CONTROLLED (	
DESCRIPTION:	ESCRIPTION: SC-88A (SC-70-5/SOT-353)				

onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.





XM

= Specific Device Code

Х

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " .", may or may not be present.

Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98AON30313E UDFN6, 1.45x1.0, 0.5P **DESCRIPTION:** PAGE 1 OF 1 onsemi and OnSemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves

the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



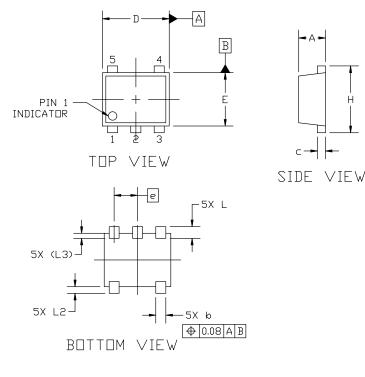
SOT-953 1.00x0.80x0.37, 0.35P CASE 527AE ISSUE F

#### DATE 17 JAN 2024

DUSEM

NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- 2. CONTROLLING DIMENSION: MILLIMETERS.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.



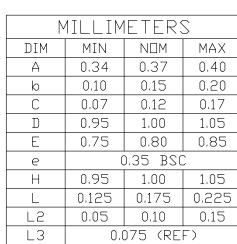
GENERIC MARKING DIAGRAM\*

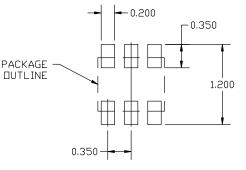


- X = Specific Device Code M = Month Code
- \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON26457D Electronic versions are uncontrolled except when accessed directly from the Document Repos Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.						
DESCRIPTION:	SOT-953 1.00x0.80x0.37, 0	PAGE 1 OF 1					
onsemi and ONSEMi are trademarks of Semiconductor Components Industries. LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves							

the right to make changes without further notice to any products herein. **onsemi** makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. **onsemi** does not convey any license under its patent rights of others.





# RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>